

isc N-Channel MOSFET Transistor

SPD03N60C3,ISPD03N60C3

FEATURES

- Static drain-source on-resistance: $R_{DS}(on) \le 1.4 \Omega$
- Enhancement mode:
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

- · High peak current capability
- · Improved transconductance

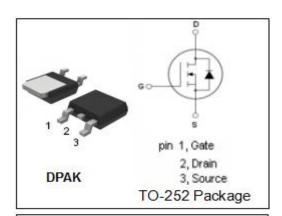


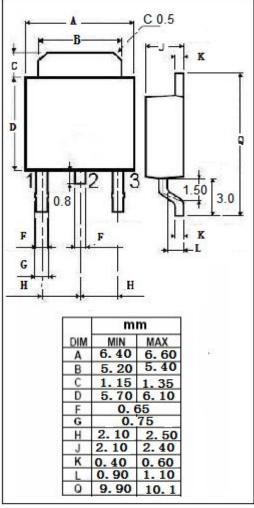
ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	600	V
V _{GS}	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous	3.2	А
I _{DM}	Drain Current-Single Pulsed	9.6	А
P_D	Total Dissipation @T _C =25°C	38	W
Tj	Max. Operating Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature	-55~150	$^{\circ}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(j-c)	Channel-to-case thermal resistance	3.3	°C/W
Rth(j-a)	Channel-to-ambient thermal resistance	75	°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =0.25mA	600			V
$V_{\text{GS(th)}}$	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.135mA	2.1		3.9	V
$R_{DS(on)}$	Drain-Source On-Resistance	V _{GS} =10V; I _D =2A			1.4	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} =30V; V _{DS} =0V			0.1	μ A
I _{DSS}	Drain-Source Leakage Current	V _{DS} =600V; V _{GS} = 0V			1	μ А
V_{SD}	Diode forward voltage	$I_F=I_S$, $V_{GS}=0V$			1.2	V

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